

STTA806D/DI/G**THERMAL AND POWER DATA**

Symbol	Parameter		Conditions	Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	TO-220AC / D ² PAK TO-220AC ins.		2.2 3.3	°C/W
P_1	Conduction power dissipation $I_{F(AV)} = 8A$ $\delta = 0.5$	TO-220AC / D ² PAK TO-220AC ins.	$T_c = 118^\circ C$ $T_c = 102^\circ C$	14.5	W
P_{max}	Total power dissipation $P_{max} = P_1 + P_3$ ($P_3 = 10\% P_1$)	TO-220AC / D ² PAK TO-220AC ins.	$T_c = 115^\circ C$ $T_c = 97^\circ C$	16	W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
V_F^*	Forward voltage drop	$I_F = 8A$	$T_j = 25^\circ C$ $T_j = 125^\circ C$		1.25	1.75 1.5	V V
I_R^{**}	Reverse leakage current	$V_R = 0.8 \times V_{RRM}$	$T_j = 25^\circ C$ $T_j = 125^\circ C$		1.5	100 4	μA mA
V_{to}	Threshold voltage	$I_p < 3 \cdot I_{AV}$	$T_j = 125^\circ C$			1.15	V
r_d	Dynamic resistance					43	m Ω

Test pulse : * $t_p = 380 \mu s$, $\delta < 2\%$ ** $t_p = 5 ms$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + r_d \times I_F^2(RMS)$$

DYNAMIC ELECTRICAL CHARACTERISTICS**TURN-OFF SWITCHING**

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ C$ $I_F = 0.5 A$ $I_R = 1 A$ $I_{rr} = 0.25 A$ $I_F = 1 A$ $di_F/dt = -50 A/\mu s$ $V_R = 30 V$		25	52	ns
I_{RM}	Maximum reverse recovery current	$T_j = 125^\circ C$ $V_R = 400 V$ $I_F = 8 A$ $di_F/dt = -64 A/\mu s$ $di_F/dt = -500 A/\mu s$		14	5.5	A
S factor	Softness factor	$T_j = 125^\circ C$ $V_R = 400 V$ $I_F = 8 A$ $di_F/dt = -500 A/\mu s$		0.47		-

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	$T_j = 25^\circ C$ $I_F = 8 A$, $di_F/dt = 64 A/\mu s$ measured at, $1.1 \times V_{Fmax}$			500	ns
V_{Fp}	Peak forward voltage	$T_j = 25^\circ C$ $I_F = 8 A$, $di_F/dt = 64 A/\mu s$			10	V

Fig. 1: Conduction losses versus average current.

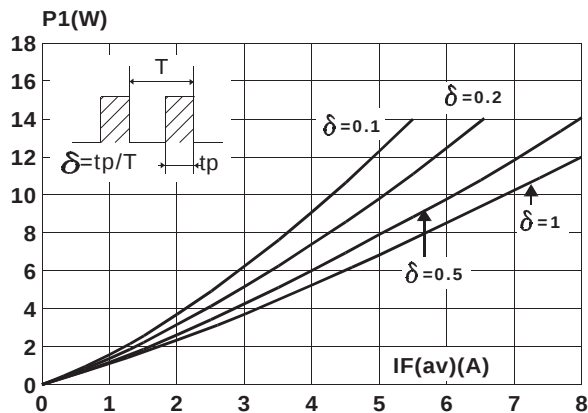


Fig. 2: Forward voltage drop versus forward current.

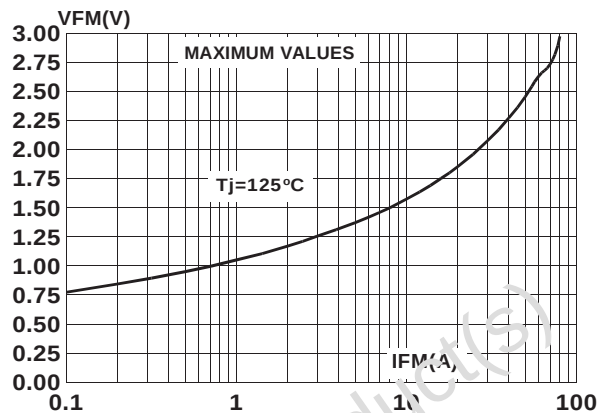


Fig. 3: Relative variation of thermal transient impedance junction to case versus pulse duration.

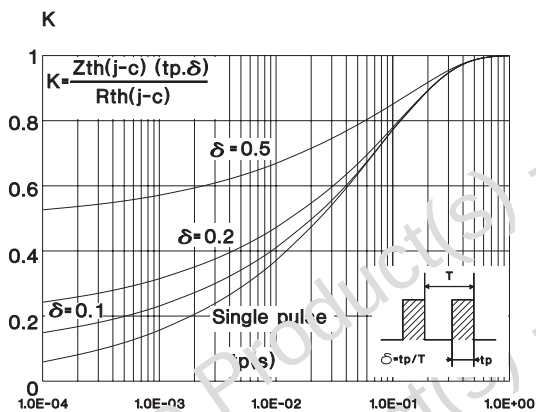


Fig. 4: Peak reverse recovery current versus diF/dt.

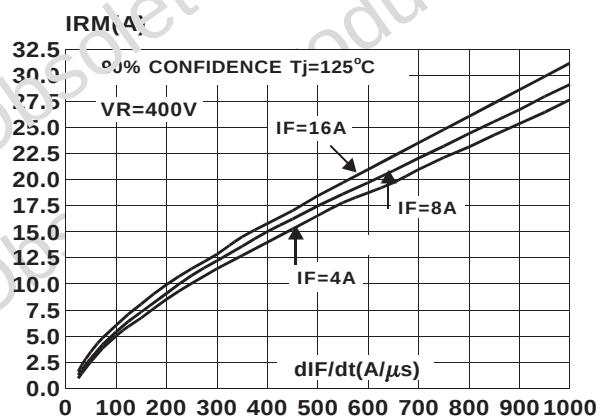


Fig. 5: Reverse recovery time versus diF/dt.

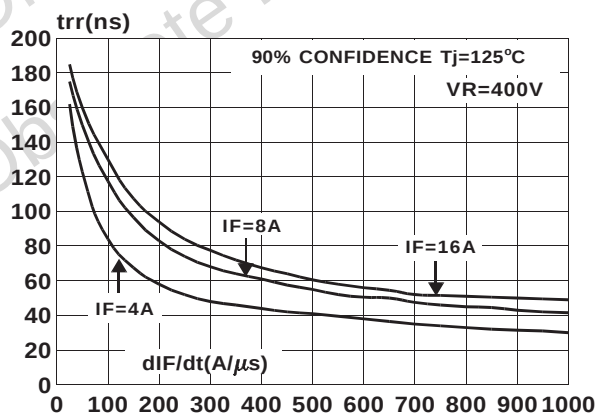


Fig. 6: Softness factor (tb/ta) versus diF/dt.

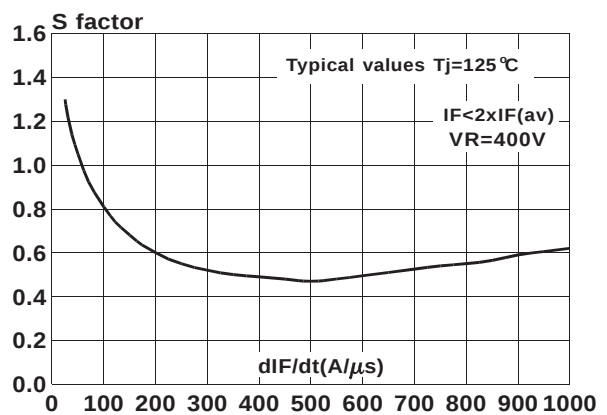


Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference $T_j=125^\circ\text{C}$).

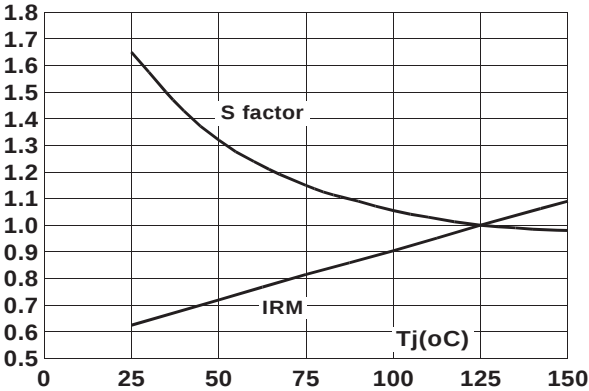


Fig. 8: Transient peak forward voltage versus dI_F/dt .

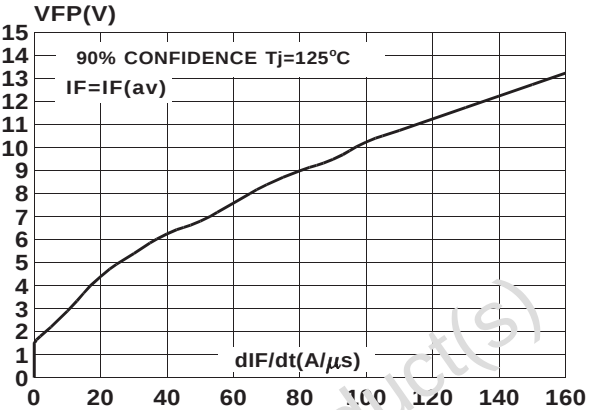
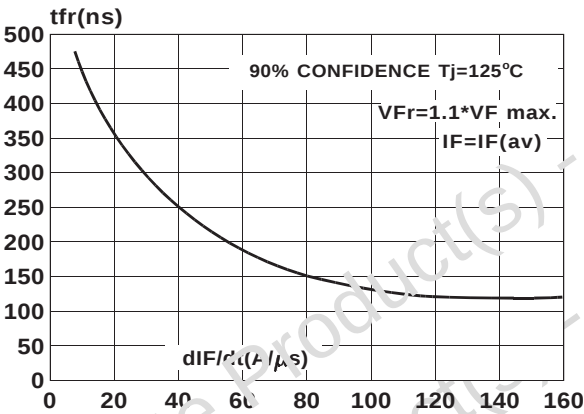


Fig. 9: Forward recovery time versus dI_F/dt .



APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion

transistor, thus optimizing the overall performance in the end application. The way of calculating the power losses is given below:

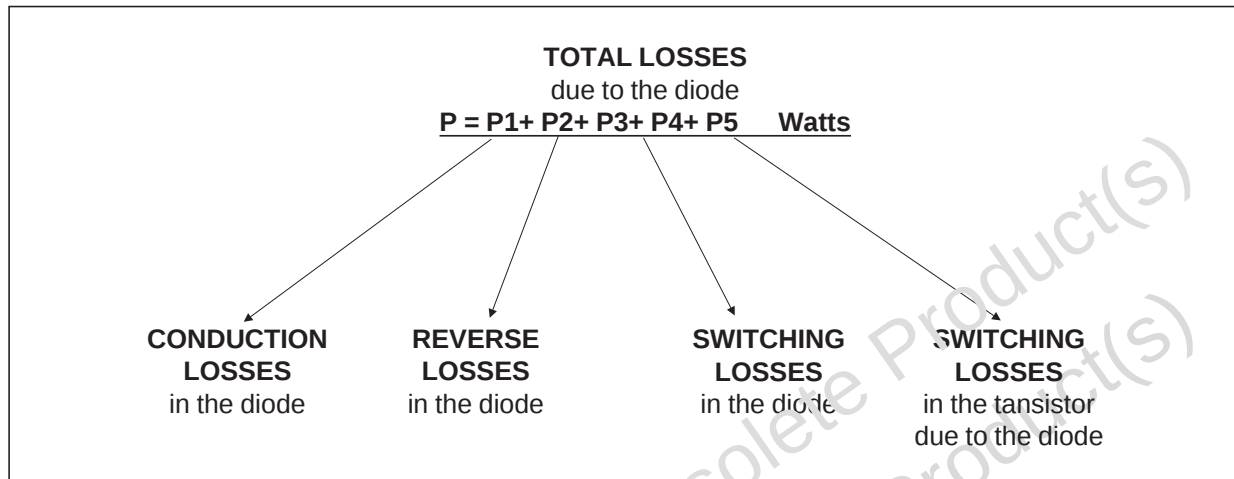
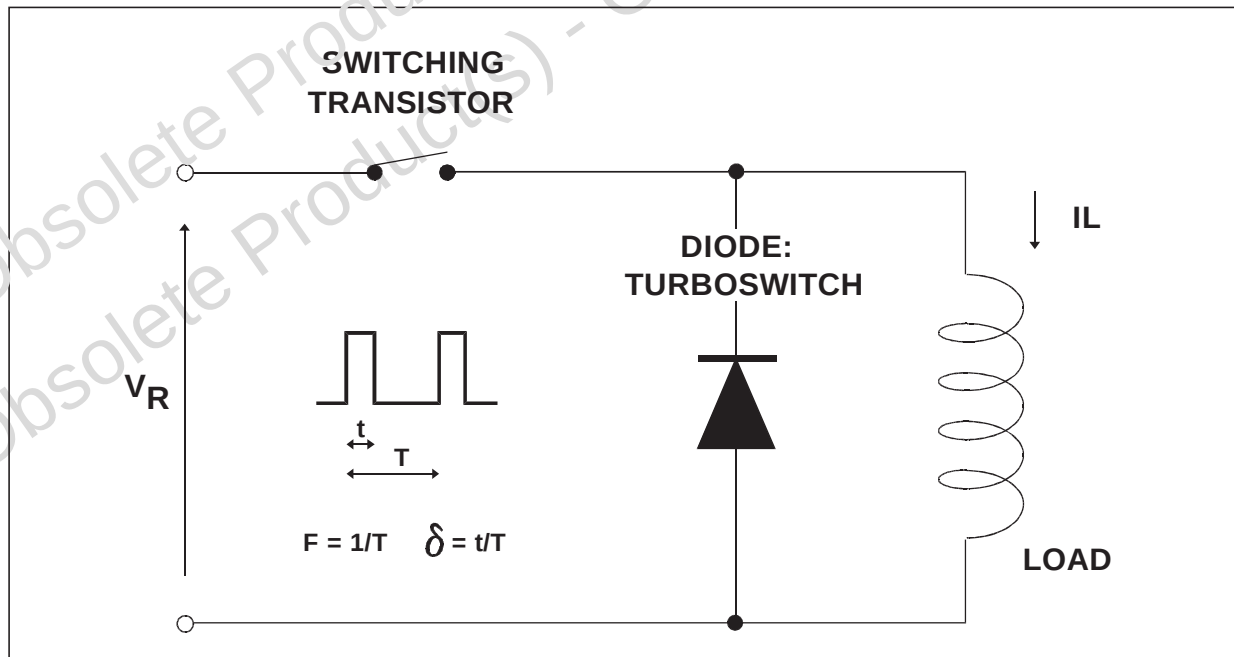
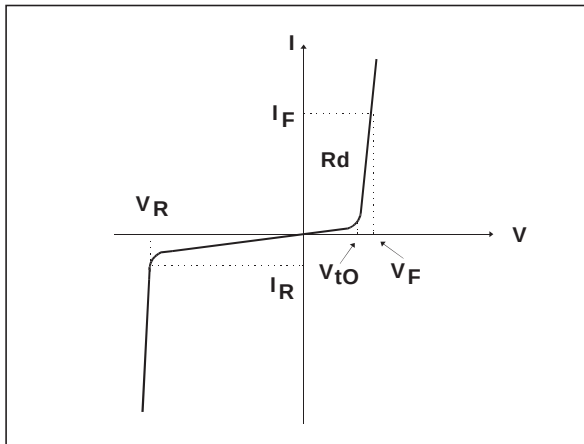


Fig. A : "FREEWHEEL" MODE



APPLICATION DATA (Cont'd)

Fig. B: STATIC CHARACTERISTICS

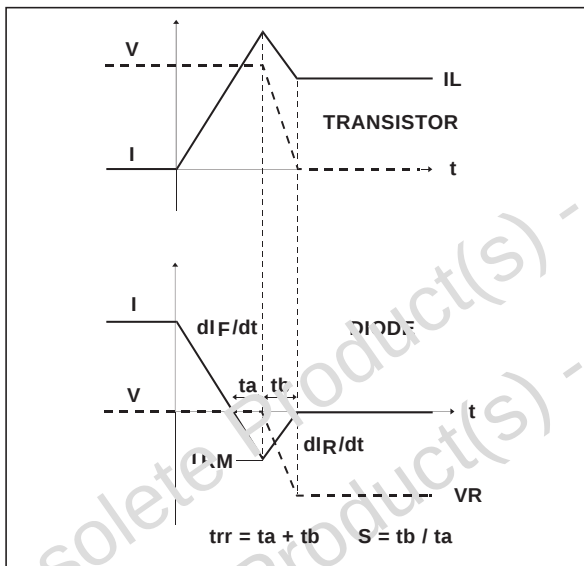
**Conduction losses :**

$$P1 = V_{t0} \cdot I_{F(AV)} + R_d \cdot I_F^2(RMS)$$

Reverse losses :

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

Fig. C: TURN-OFF CHARACTERISTICS

**Turn-on losses :**

(in the transistor, due to the diode)

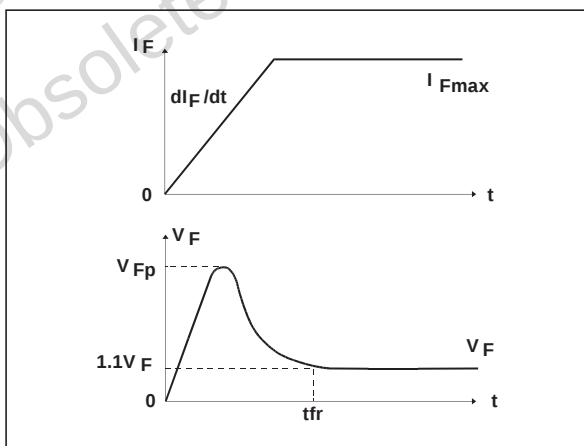
$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F / dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F / dt}$$

Turn-off losses (in the diode) :

$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F / dt}$$

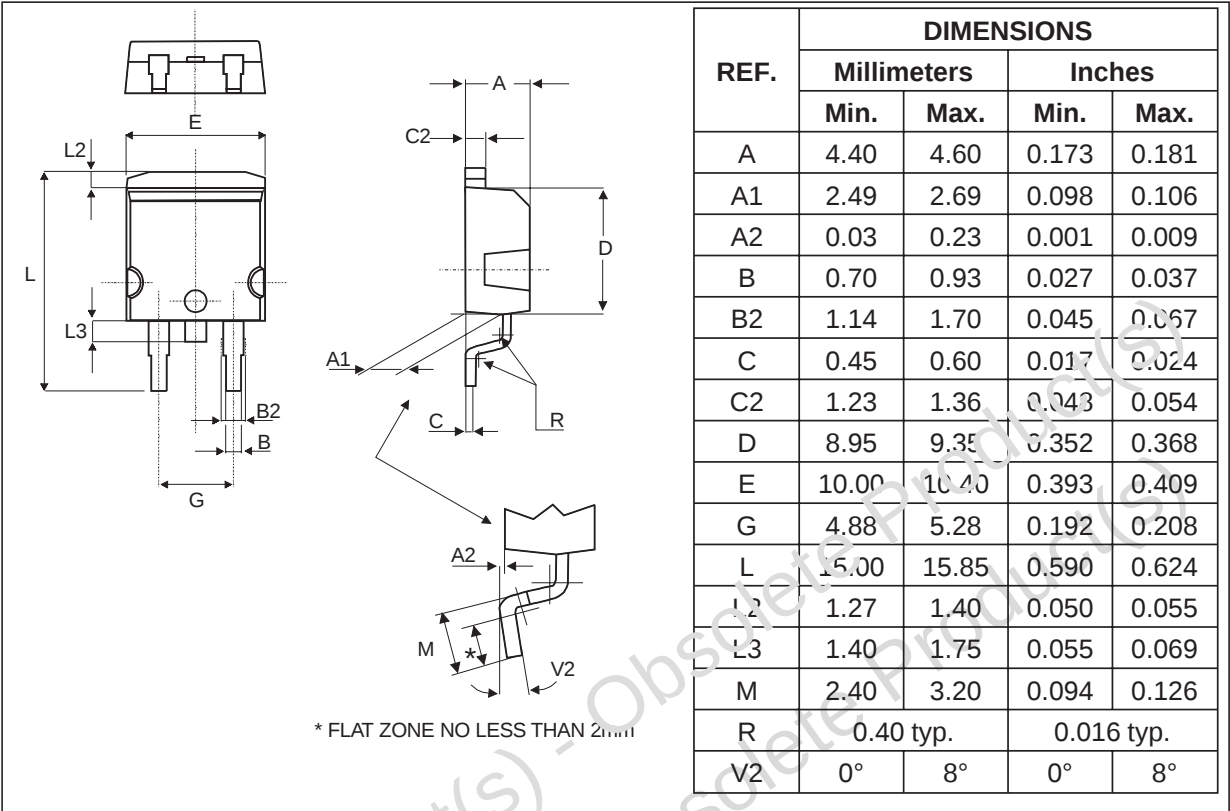
P3 and P5 are suitable for power MOSFET and IGBT

Fig. D: TURN-ON CHARACTERISTICS

**Turn-on losses :**

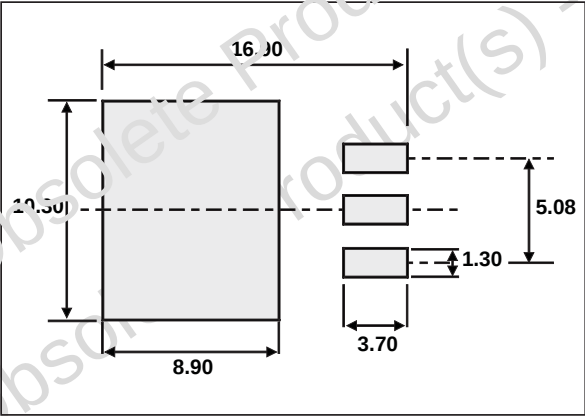
$$P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{fr} \cdot F$$

PACKAGE DATA
D²PAK



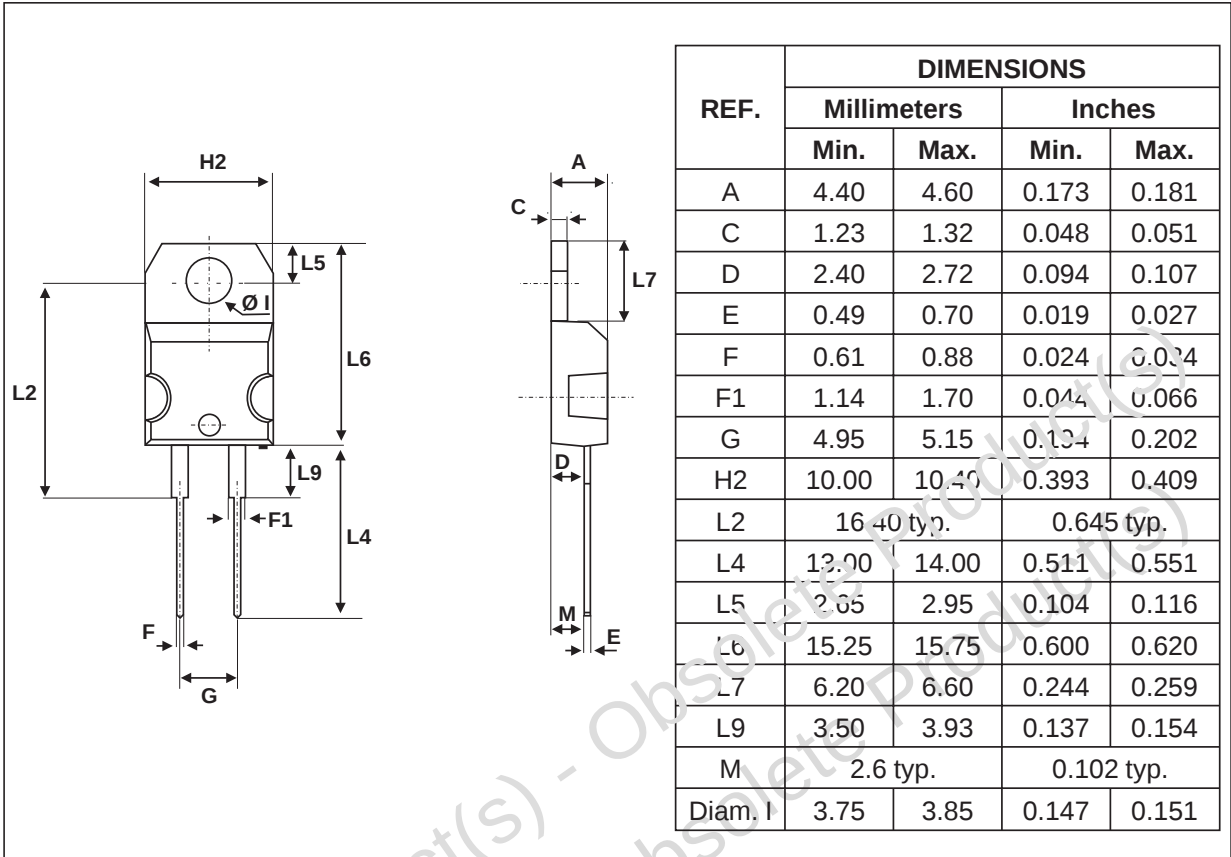
FOOTPRINT DIMENSIONS (in millimeters)

■ Cooling method : by conduction (C)

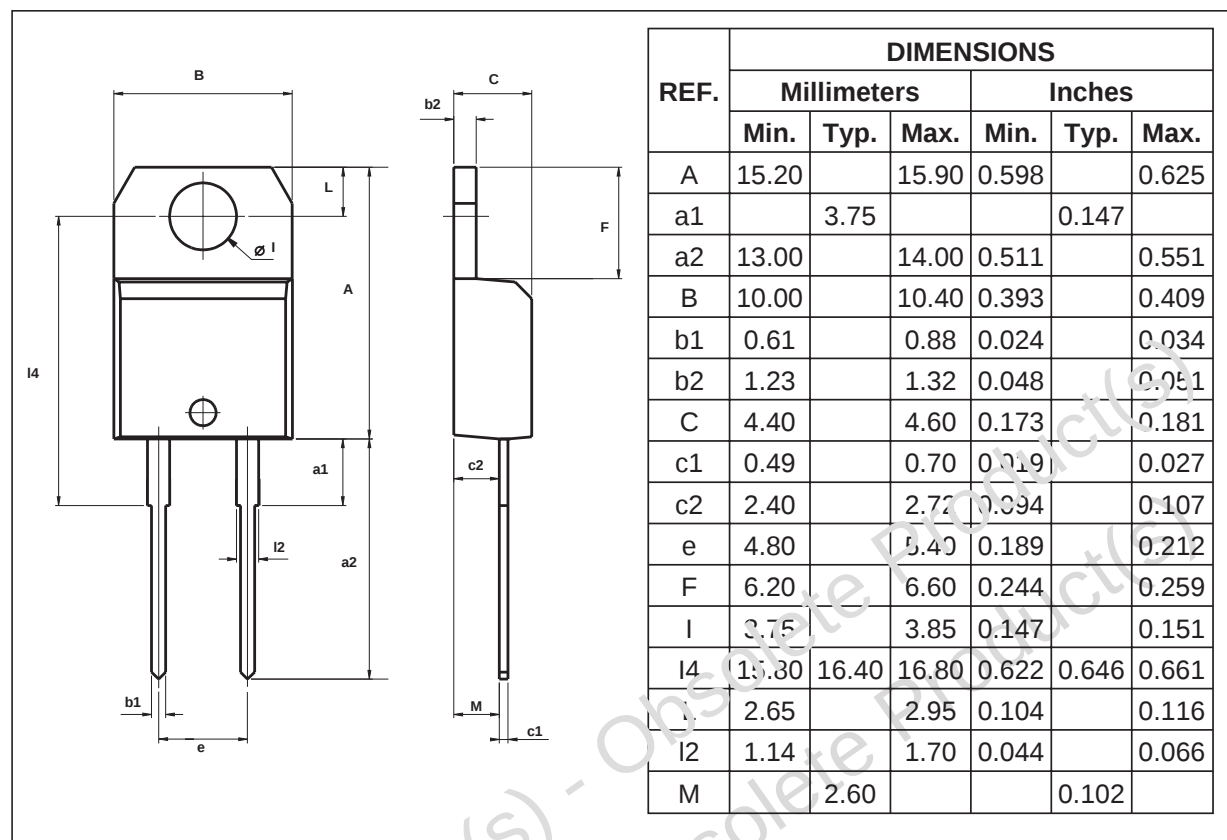


STTA806D/DI/G

PACKAGE DATA
TO-220AC (JEDEC OUTLINE)



- Cooling method : by conduction (C)
- Recommended torque value : 0.55m.N
- Maximum torque value : 0.7m.N

PACKAGE DATA
 INSULATED TO-220AC


- Cooling method : by conduction (C)
- Recommended torque value : 0.3m.N
- Maximum torque value : 1m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA806D	STTA806D	TO-220AC	1.86g	50	Tube
STTA806DI	STTA806DI	TO-220AC Ins.	1.86g	250	Bulk
STTA806G	STTA806G	D ² PAK	1.48g	50	Tube
STTA806G-TR	STTA806G	D ² PAK	1.48g	500	Tape & reel

- Epoxy meets UL94,V0

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